Phase Control Thyristor Stud Types N0290SX120 to N0290SX160

The data sheet on the subsequent pages of this document is a scanned copy of existing data for this product. (Rating Report 86TR10 Issue 1)

This data reflects the old part number for this product which is: N170PH02-15. This part number must <u>NOT</u> be used for ordering purposes – please use the ordering particulars detailed below.

The limitations of this data are as follows: Only SC outline drawing (W18) in datasheet No reverse recovery information available Device no longer available for grades 02 to 10 (200V to 1000V V_{RRM}/V_{DRM})

The following links will direct you to the appropriate outline drawings <u>Outline W18</u> – ¾" Ceramic stud <u>Outline W25</u> – ¾" Ceramic stud removed

Where any information on the product matrix page differs from that in the following data, the product matrix must be considered correct

An electronic data sheet for this product is presently in preparation.

For further information on this product, please contact your local ASM or distributor.

Alternatively, please contact Westcode as detailed below.

Ordering Particulars						
N0290	SX	* *	0			
Fixed Type Code	SC – ¾" Ceramic stud SD – ¾" Ceramic stud removed	Voltage code V _{RRM} /100 12-16	Fixed Code			

Typical Order Code: N0290SD140, 3⁄4" Ceramic stud removed, 1400V V_{RRM}/V_{DRM}

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In the interest of product improvement, Westcode reserves the right to change specifications at any time without prior notice.

Devices with a suffix code (2-letter, 3-letter or letter/digit/letter combination) added to their generic code are not necessarily subject to the conditions and limits contained in this report.

QUALITY EVALUATION LABORATORY

Rating Report: 86TR10 Origin:

Date : 3rd July, 1986 Pages : 12

Thyristor Type N170PH02-H15

Checked: MAN Written: Mr. Muslop Approved:

The thyristor consists of a diffused silicon slice of 24 mm diameter mounted under spring pressure in a stud base, top hat housing with flexible lead. This Report supersedes Rating Report No. 79TR26 (Issue 2)

Ratings Voltage Grades : HO2-H15 V_{DSM} 200-1500V V_{RSM} 300-1600V V_{DRM}, V_{RRM} 200-1500V $\rm I_{T}\,(AV)$: Single phase : 50 Hz, 180° sinewave $T_{CASE} = 85^{\circ}C$: 196A I_T(rms) max. 355A • I_T d.c. max. : 355A I_{TSM} : t = 10ms half sinewave; $T_{J}(initial) = 125^{\circ}C: V_{RM} = 0.6V_{RRM}(MAX)$: 4200A ITSM : t = 10ms half sinewave; T_j(initial) = 125°C: $V_{RM} \leq 10V$: 4620A $I^{2}t$: t = 10 ms; T_J(initial) = 125^oC : ^VRM = 0.6V_{RRM}(MAX) : 88.2 x 10³A²s $I^2 t :: t = 10 \text{ ms}; T_j(\text{initial}) = 125^{\circ}C : V_{RM} \leq 10V$: 106.7 x $10^3 \text{A}^2 \text{s}$ I^2 t : t = 3 ms; T_J(initial) = 125°C : V_{RM} < 10V : 79.4 x $10^3 A^2 S$ di/dt : (Repetitive) T = 125°C Gate: 20V 20 _ Rise time 1µS : 500A/uS $\mathbf{I}_{\mathsf{FGM}}$: Anode positive with respect to cathode : 20A V_{EGM} : Ħ 11 11 11 : 18V V_{RGM} : 5V P_G(AV) : : 2W P_{GM}: : 100W V_{БD} : : 0.25V T_C operating range : -40 to 125°C T_{stg} Non-operating : -40 to 150°C

<u>Characteristics</u>

(maximum values unless stated otherwise)

 $I_{GT} : T_{J} = 25^{\circ}C$: 150mA $I_{H} : T_{J} = 25^{\circ}C$) $V_{A} = {}^{6V}$; $I_{A} = {}^{1A}$ $V_{GT} : T_{J} = 25^{\circ}C$) : 600mA : 3V V_0 : $T_j = 125^{\circ}C$: 1.08V r_{T} : $T_{1} = 125^{\circ}C$: 1.3mohms V_{TM} : $I_{TM} = 616A$ $T_{V,I} = 125^{\circ}C$: 1.88V R_{th} (J/C) : 0.12°C/W dV/dt: Linear ramp to 0.8V (max). T = 125°C: Gate 0/C; repetitive : 200V/uS* I_{DRM} : $T_{J} = 125^{\circ}C V_{DM} = V_{DRM}(max)$: 20mA I_{RRM} : $T_{J} = 125^{\circ}C V_{RM} = V_{RRM}(max)$: 20mA Q_{RR} : I_{TM} = dI/dt A/uS, 50% chord value $V_{\rm RM}$: $T_{\rm VJ} = 125^{\circ}{\rm C}$: dI/dt A/uS; T_J = 125^oC V_{RM} = 50V tq : I_{TM} $dV/dt = 200V/uS \text{ to } 0.8V_{DRM}$ When specified, 20V/uS to 0.8V $_{\rm NRM}$ Typical : Outline drawing · 101A225 R_{tb} (C-H.S.) : 0.04°C/W Mounting torque [•] 2.5 - 2.77Kg.m Outline (JEDEC NO.) :

*Repetitive dv/dt

Higher dv/dt selections are available up to 1000V/uS on request.

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Changes to 79TR26 (Issue 2)

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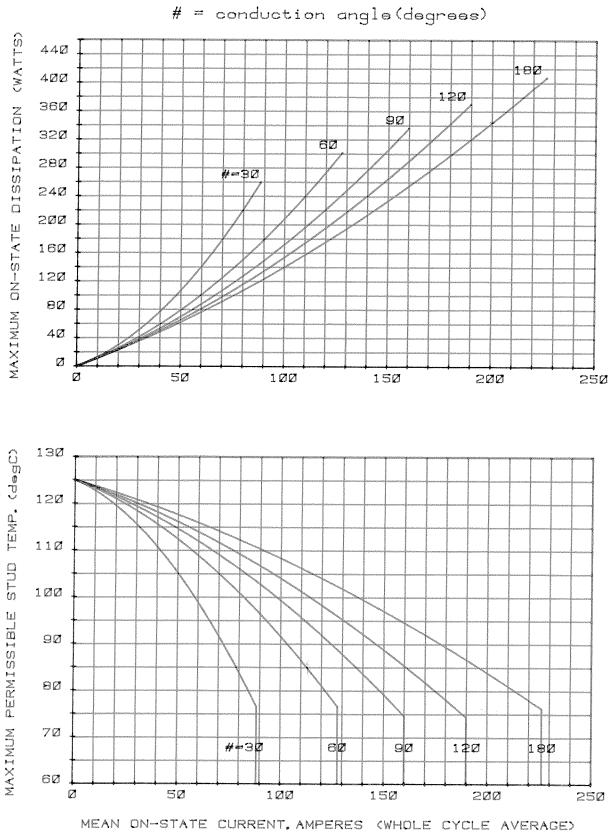
p1	V_{DWM} , V_{RWM} deleted		
	I_{FGM} increased to 20A		
	$^{\mathrm{T}}_{\mathrm{HS}}$ operating range MIN decreased to -40°C		
p2	: $I_{L}(=200 \text{mA})$ changed to I_{H} at 6V, 1A = 600 \text{mA}		
	Note 1 deleted; replaced by dV/dt note.		
p7	: $I_{T} - V_{T}, Z_{th-t}$ now on separate pages		
Nev	$^{\prime}$ p9: $^{V}_{G}$ - $^{I}_{G}$: $^{I}_{FGM}$ increased to 20A		
Nev	v p10: I $_{ m GT}$ – V $_{ m GT}$: axes interchanged		

<u>Voltage Ratings</u>

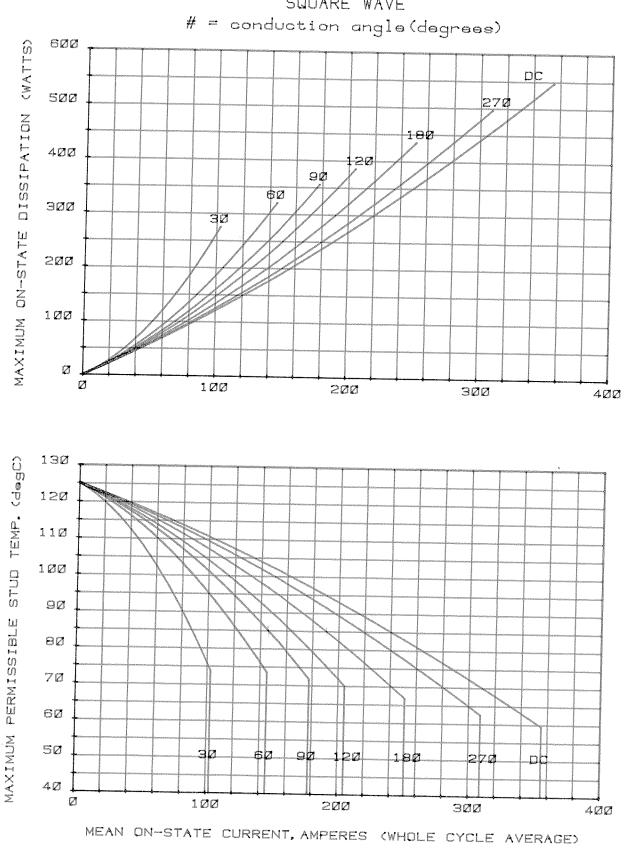
Voltage Grade	V _{DSM} V _{DRM} V _{RRM}	V _{RSM}	V _D V _R
•H•	V	V	DC
02	200	0.00	
		300	140
03	300	400	210
04	400	500	260
06	600	700	420
08	800	900	560
10	1000	1100	700
12	1200	1300	810
14	1400	1500	930
15	1500	1600	980

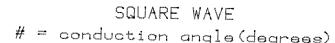
Extension of Voltage Grades

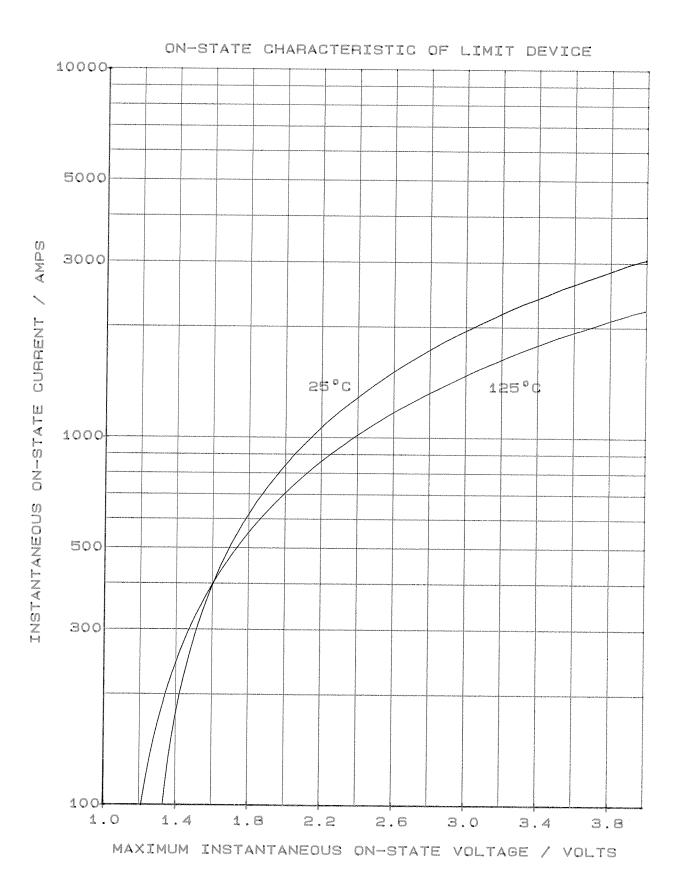
This report is applicable to other and higher voltage grades when supply has been agreed by Sales/Production.



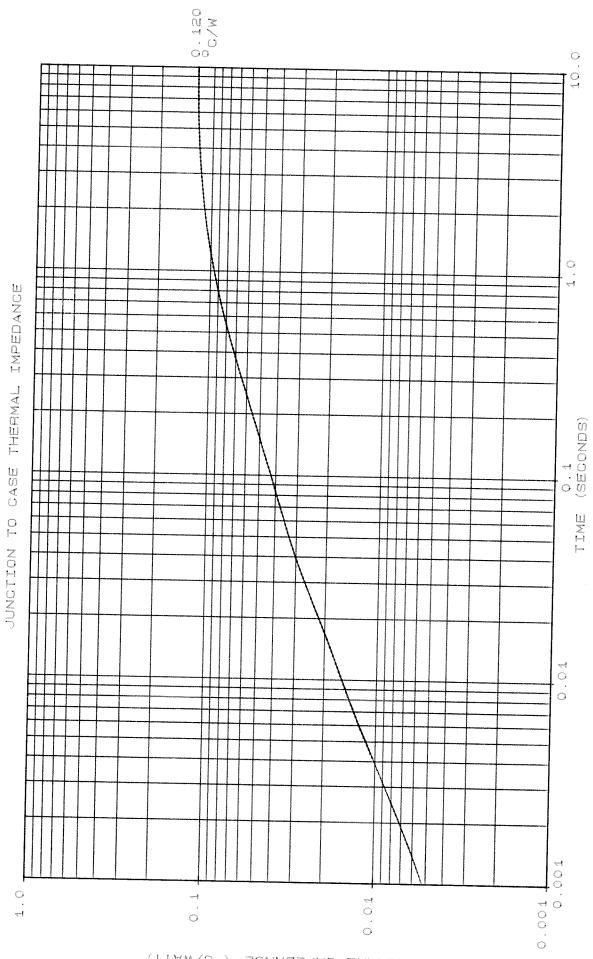
SINE WAVE







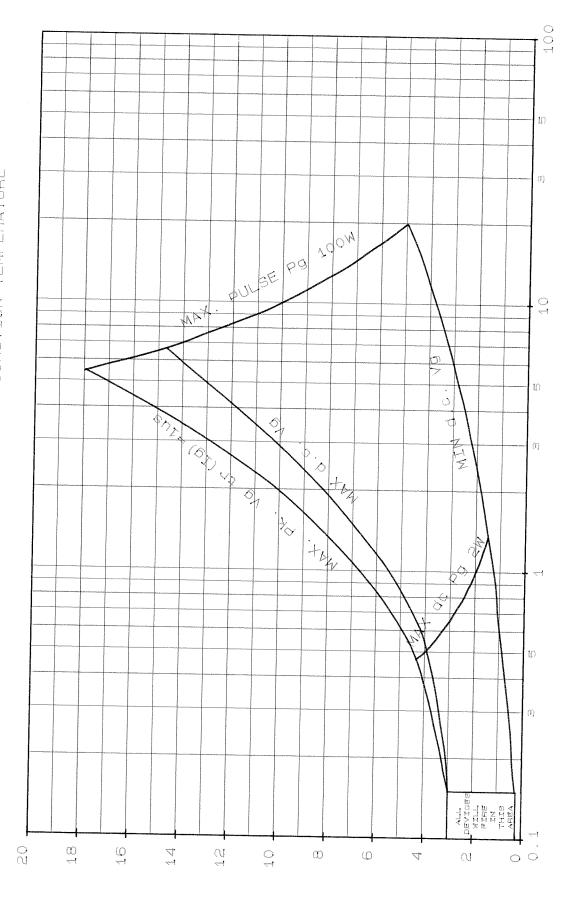
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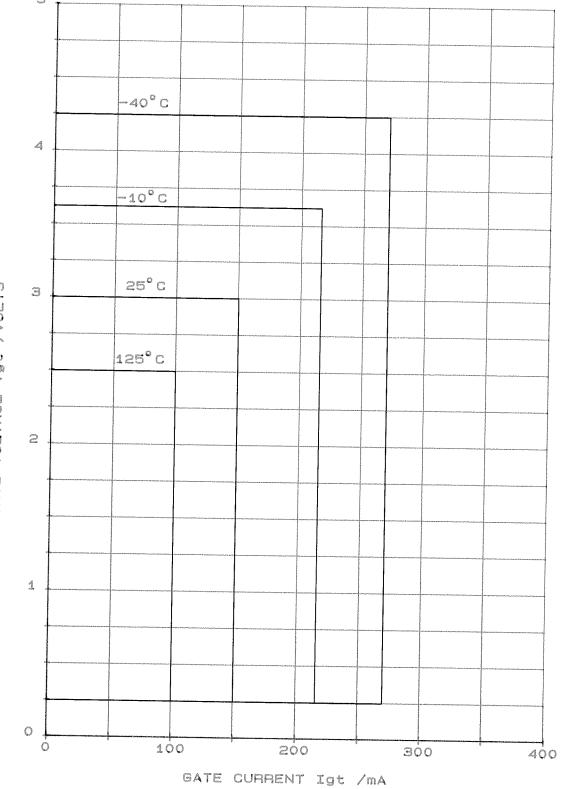
(TTAWNO) BONADEGMI JAMPEHT

GATE CHARACTERISTICS AT 25°C JUNCTION TEMPERATURE



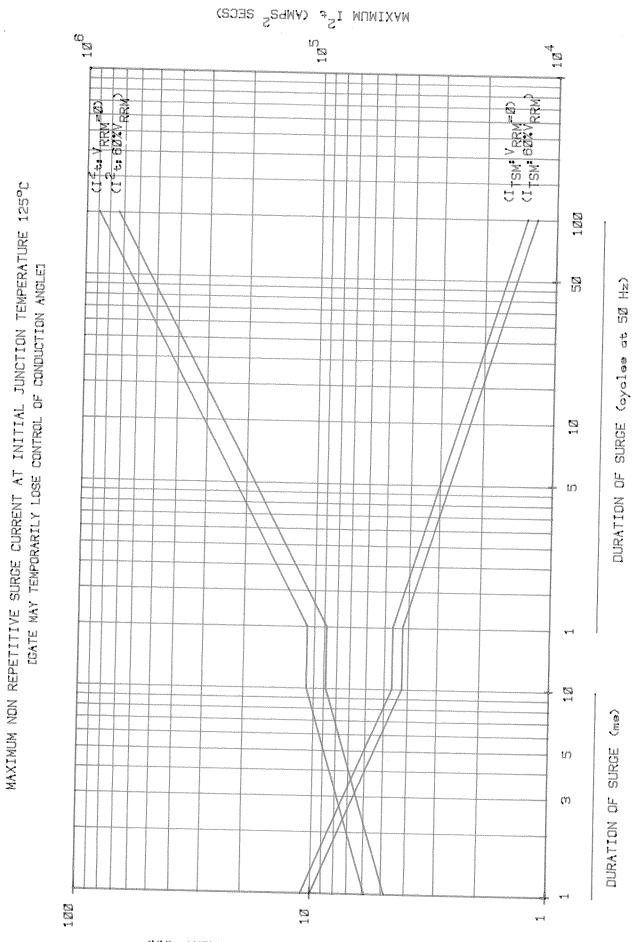
(STIOV) (UV) EAA (VOLTS)

GATE CURRENT (AMPS)



GATE VOLTAGE Vgt /VOLTS

GATE TRIGGERING CHARACTERISTICS (TRIGGER POINTS OF ALL THYRISTORS LIE IN THE AREAS SHOWN)



TOTAL PEAK HALF SINE SURGE CURRENT (KA)

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SCALE 1/1 INTERNATIONAL OUTLINE No. DRN WEIGHT. 280 GRAMS APPX. TYPE NUMBER P200P FINISH. BRIGHT NICKEL PLATE. NI7OP CHKD P202P DEVICE MARKING INCLUDES MONOGRAM, TYPE No., SPEC. APPD P204P N195P No. AND POLARITY SYMBOL. P205P DEVICE MOUNTING: MOUNTING TORQUE N275P P214P 27-24.5 Nm (2.77-2.5 kgF-m). P215P THREAD MUST NOT BE LUBRICATED. P270P NOTES. A 103A162 G.A. DRG. No. NI S Ø 7.8 MAX 19 MAX 8.8 8.2 Ø FOR M4 OR Nº SUNC SCREW. || -MIN FLAT COLOUR RED COLOUR WHITE MIN BEND HEIGHT 210 + 10 \$27.4 MAX 30 31.62 31.42 PERM Al 3.6/2 U'CUT NGHOUS X A M X Ø 16.8 MIN. $\overline{\heartsuit}$ 3"- KUNF - 2A INFOR ND IS PRO INFORMATI EXCEPT W AWING ШН WESTINGHOUSE BRAKE AND SIGNAL CO. LTD. WESTCODE ® CHIPPENHAM, WILTSHIRE, SN15 1JD, ENGLAND. SEMICONDUCTORS 27.11.84 MI218 -11.78 M670 ₹¢ Mir こが THIRD ANGLE PROJECTION # 8.8/8.2 HOLE REVISIONS PE Nº ADE ш 45 10.7/10.2 2 RED& WHITE WERE VIOLET & 12.79 MB WAS 9 DIMNS. IN MILLIMETRES NAME がの DRG. No. |0|A22SS ŝ 2 4 S ق 5355E OZALID (U.K) LTD